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High Performance Schottky Rectifier, 18 A

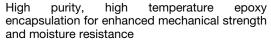


D ² PAK (TO-263AB

PRIMARY CHARACTERISTICS						
I _{F(AV)}	18 A					
V _R	35 V, 40 V, 45 V					
V _F at I _F	0.53 V					
I _{RM}	25 mA at 125 °C					
T _J max.	175 °C					
E _{AS}	24 mJ					
Package	D ² PAK (TO-263AB)					
Circuit configuration	Single					

FEATURES

- 175 °C T_J operation
- Low forward voltage drop
- High frequency operation





- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The VS-18TQ... Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	VALUES	UNITS					
I _{F(AV)}	Rectangular waveform	18	Α				
V _{RRM}	Range	35 to 45	V				
I _{FSM}	t _p = 5 μs sine	1800	Α				
V _F	18 A _{pk} , T _J = 125 °C	0.53	V				
TJ	Range	-55 to +175	°C				

VOLTAGE RATINGS								
PARAMETER SYMBOL VS-18TQ035S-M3 VS-18TQ040S-M3 VS-18TQ045S-M3 UNITS								
Maximum DC reverse voltage	V_R	35	40	45	W			
Maximum working peak reverse voltage	V_{RWM}	33	40	45	V			

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDI	VALUES	UNITS			
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T _C = 149 °C	18	А			
Maximum peak one cycle		5 μs sine or 3 μs rect. pulse	Following any rated	1800	А		
non-repetitive surge current See fig. 7	I _{FSM}	10 ms sine or 6 ms rect. pulse	load condition and with rated V _{RRM} applied	390			
Non-repetitive avalanche energy	E _{AS}	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 3.6 \text{A}, L = 3.7 \text{mH}$		24	mJ		
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T_J maximum $V_A = 1.5 \times V_R$ typical		3.6	А		

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ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS					
		18 A	- T _{.I} = 25 °C	0.60	V			
Maximum forward voltage drop See fig. 1	V _{FM} ⁽¹⁾	36 A	1j = 25 C	0.72				
		18 A	- T _{.I} = 125 °C	0.53				
		36 A	1j = 125 C	0.67				
Maximum reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C	V _B = Rated V _B	2.5	mA			
See fig. 2	IRM (')	T _J = 125 °C	v _R = nateu v _R	25	IIIA			
Maximum junction capacitance	C _T	V _R = 5 V _{DC} (test signal ran	1400	pF				
Typical series inductance	L _S	Measured lead to lead 5	8.0	nH				
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs			

Note

 $^{^{(1)}\,}$ Pulse width < 300 µs, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction and storage temperature rar	nge	T _J , T _{Stg}	J, T _{Stg}		°C			
Maximum thermal resistance, junction to case		R _{thJC}	DC operation See fig. 4	1.50				
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth, and greased	0.50	°C/W			
Annyayimata waisht				2	g			
Approximate weight				0.07	OZ.			
Manustina tauana	minimum			6 (5)	kgf · cm			
Mounting torque	maximum			12 (10)	(lbf · in)			
Marking device				18TQ035S				
			Case style D ² PAK (TO-263AB)	18TQ	040S			
				18TQ	045S			

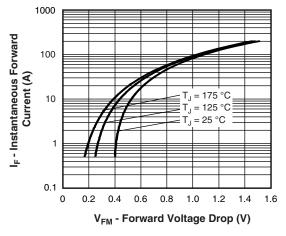


Fig. 1 - Maximum Forward Voltage Drop Characteristics

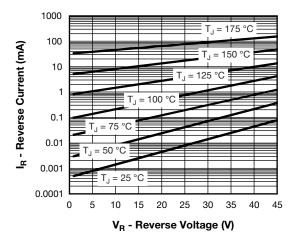


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

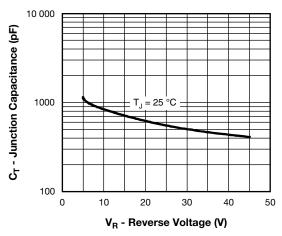


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

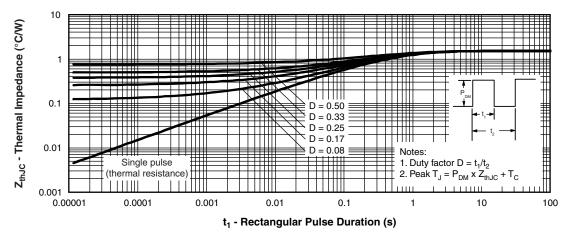


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

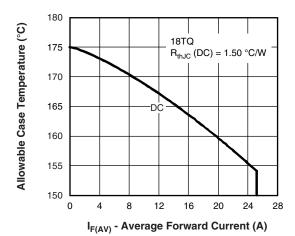


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

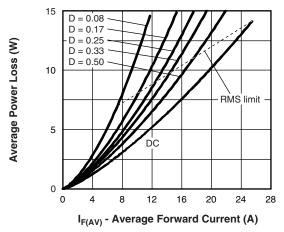
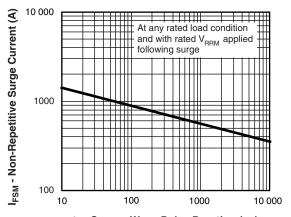


Fig. 6 - Forward Power Loss Characteristics

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 t_{p} - Square Wave Pulse Duration (μ s)

Fig. 7 - Maximum Non-Repetitive Surge Current

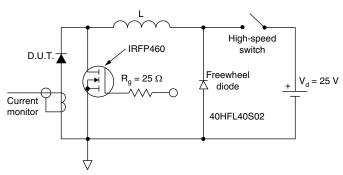


Fig. 8 - Unclamped Inductive Test Circuit

ORDERING INFORMATION TABLE

Device code VS-18 T Q 045 S **TRL** -M3 2 (3) 4 5 6 (8) Vishay Semiconductors product

Circuit configuration T. TO 200

Circuit configuration: T = TO-220

 Schottky "Q" series
Voltage ratings
S = D²PAK (TO-263AB)
035 = 35 V 040 = 40 V 045 = 45 V

7 - • None = tube

• TRL = tape and reel (left oriented)

TRR = tape and reel (right oriented)

8 - -M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free



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ORDERING INFORMATION								
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-18TQ035S-M3	50	1000	Antistatic plastic tubes					
VS-18TQ035STRR-M3	800	800	13" diameter reel					
VS-18TQ035STRL-M3	800	800	13" diameter reel					
VS-18TQ040S-M3	50	1000	Antistatic plastic tubes					
VS-18TQ040STRR-M3	800	800	13" diameter reel					
VS-18TQ040STRL-M3	800	800	13" diameter reel					
VS-18TQ045S-M3	50	1000	Antistatic plastic tubes					
VS-18TQ045STRR-M3	800	800	13" diameter reel					
VS-18TQ045STRL-M3	800	800	13" diameter reel					

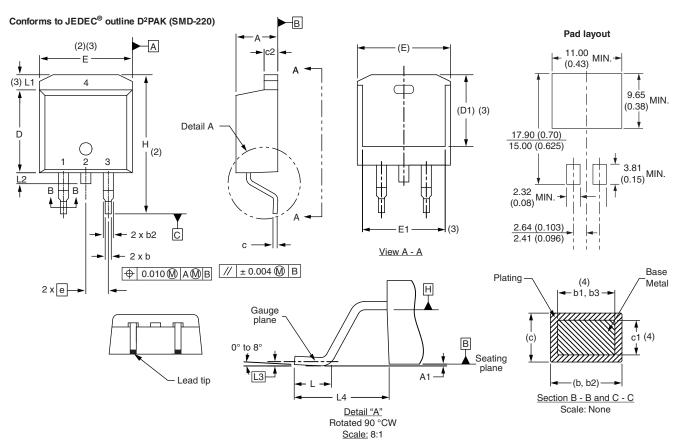
LINKS TO RELATED DOCUMENTS						
Dimensions	www.vishay.com/doc?96164					
Part marking information	www.vishay.com/doc?95444					
Packaging information	www.vishay.com/doc?96424					
SPICE model	www.vishay.com/doc?96209					



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D²PAK

DIMENSIONS in millimeters and inches



SYMBOL	MILLIM	ETERS	INCHES		NOTES	NOTES SYMBOL	MILLIM	ETERS	INC	HES	NOTES	
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOIES	NOTES	STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			Е	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100) BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

Notes

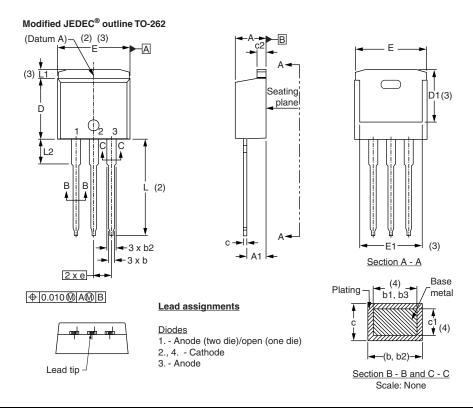
- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC® outline TO-263AB

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TO-262

DIMENSIONS in millimeters and inches



SYMBOL	MILLIN	METERS	INC	INCHES			
STINIBOL	MIN.	MAX.	MIN.	MAX.	NOTES		
Α	4.06	4.83	0.160	0.190			
A1	2.03	3.02	0.080	0.119			
b	0.51	0.99	0.020	0.039			
b1	0.51	0.89	0.020	0.035	4		
b2	1.14	1.78	0.045	0.070			
b3	1.14	1.73	0.045	0.068	4		
С	0.38	0.74	0.015	0.029			
c1	0.38	0.58	0.015	0.023	4		
c2	1.14	1.65	0.045	0.065			
D	8.51	9.65	0.335	0.380	2		
D1	6.86	8.00	0.270	0.315	3		
E	9.65	10.67	0.380	0.420	2, 3		
E1	7.90	8.80	0.311	0.346	3		
е	2.54 BSC		0.100) BSC			
L	13.46	14.10	0.530	0.555			
L1	-	1.65	-	0.065	3		
L2	3.36	3.71	0.132	0.146			

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- 5) Controlling dimension: inches
- (6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum), D1 (minimum) and L2 where dimensions derived the actual package outline

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